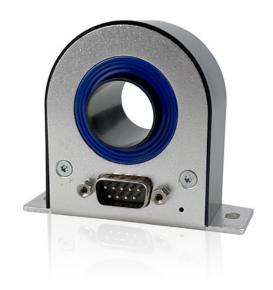


DATA SHEET

CTT200ID 200 A RMS / 200 A DC Current Transducer

SPECIAL FEATURES

- 200 A RMS nominal current
- 200 A DC nominal current
- 2 MHz bandwidth (±3 dB)
- 20.7 mm aperture for cables and bus bars
- -40 °C to +85 °C operating range
- Best in class for accuracy and stability
- Isolated AC and DC current measurements
- 1 ppm maximum linearity error
- Industry standard D-SUB 9 connector
- Full aluminum body for superior EMI shielding
- Advanced sensor protection circuits



CTT200ID Functions and Benefits

The HBM series of current transducers feature industry standard, fluxgate, closed-loop technology. The second harmonic zero flux detection ensures the highest accuracy and lowest drift while maintaining a high bandwidth.

HBM current transducers are perfect for measuring currents between 10 and 1000 A RMS. With the high bandwidth support, they can be used with fast rise time signals, such as those found in electric drives or other inverter applications, such as those in renewable industries.

The CT series is available for 50 A RMS to 1000 A RMS, all sharing the same high-end technology. All connectors are compatible for fast exchange.

The optional 1 HE 19" rack mountable power supply can power any mix of up to six CTs.

Current output cables to connect directly to the GN31XB power card, as well as to the GN61XB card, are available.

Optional burden resistors are available for the GEN series Data Acquisition Systems or power analyzers without an integrated burden resistor.

The advanced sensor protection circuit ASPC prevents sensor damage for incorrect use cases, such as currents applied to unpowered CTs or powered CTs without a burden resistor to close the current output loop.

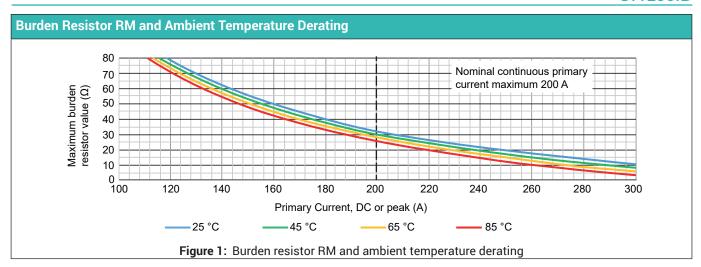
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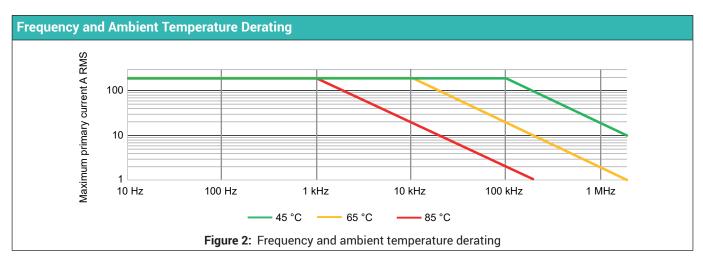
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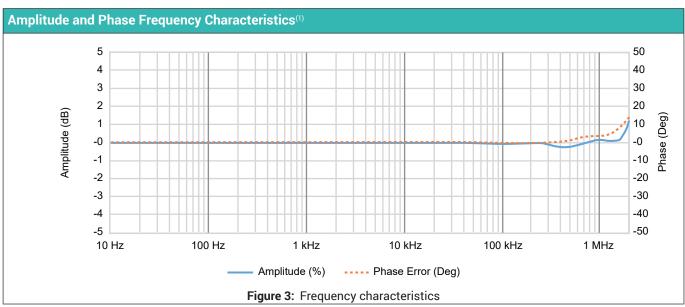
Specification Highlights					
	Symbol	Value	Comment		
Nominal primary AC current	I _{PN} AC	200 A RMS			
Nominal primary DC current	I _{PN} DC	± 200 A			
Measuring range	Î _{PM}	± 285 A			
Primary / secondary ratio	n1 : n2	1:1000			
Bandwidth	f(±3 dB)	2000 kHz	Small signal, refer to Figure 3		

Electrical Specifica	ations				
At Ta = 23 °C, supply	voltage = ± 15 V unles	s otherwise stat	ed		
Parameter		Symbol	Value	Comment	
Overload capacity		Î _{OL}	± 1000	Non-measured, 100 ms	
Linearity error		٤L	± 1 ppm	Refers to nominal DC current	
Offset current (includ	ling earth field)	I _{OE}	± 25 ppm	Refers to nominal DC current	
DC -10 Hz overall acc (= EL + IOE)		accE	± 26 ppm	Refers to nominal DC current	
Offset temperature c	oefficient	TC _{IOE}	± 0.2 ppm/K	Refers to nominal DC current	
	10 Hz - 5 kHz		± 0.01%		
A 15 1	5 kHz - 100 kHz		± 1%	See Figure 3 for details	
Amplitude error	100 kHz - 1 MHz	EG	± 10%	Refers to nominal current	
	1000 kHz - 2000 kHz		± 30%		
	10 Hz - 5 kHz		± 0.01°		
DI 1:6	5 kHz - 100 kHz		± 1°	0.5	
Phase shift	100 kHz - 1 MHz	θ	± 10°	See Figure 3 for details	
	1000 kHz - 2000 kHz		± 40°		
Response time to a s	tep current IPN	tr @ 90%	1 µs		
	0.1 Hz - 10 Hz		0.03 ppm RMS		
	0.1 Hz - 100 Hz	noise	0.5 ppm RMS		
RMS Noise	0.1 Hz - 1 kHz		0.7 ppm RMS	ppm RMS refers to nominal current	
	0.1 Hz - 10 kHz		1 ppm RMS		
	0.1 Hz - 100 kHz		6 ppm RMS		
	0.1 Hz - 10 Hz		0.3 ppm p-p		
	0.1 Hz - 100 Hz		1 ppm p-p		
Peak-to-peak noise	0.1 Hz - 1 kHz	noise	2 ppm p-p	ppm peak-to-peak refers to nominal	
•	0.1 Hz - 10 kHz		4 ppm p-p	current	
	0.1 Hz - 100 kHz		40 ppm p-p		
Fluxgate excitation f	requency	f _{Exc}	31.25 kHz		
Induced RMS voltage conductor	e on primary		5 μV RMS		
Stability					
Offset stability over t	ime	ppm/month µA/month	± 0.1 ppm/month ± 0.02 μA/month	Refers to nominal DC current µA refers to secondary current	
Impact of external m	agnetic field	ppm/mT µA/mT	± 4 ppm/mT ± 0.8 μA/mT	Refers to nominal DC current µA refers to secondary current	
Offset change with power supply voltage changes		ppm/mV µA/mV	± 0.0013 ppm/mV 0.0003 μA/mV (typical)	Refers to nominal DC current µA refers to secondary current	
Power supply					
Power supply voltage	es	Uc	± 15.75 V		
Positive current cons	sumption	Ips	40 mA + Is	Add Is (if Is is positive)	
Negative current con	sumption	Ins	35 mA + Is	Add Is (if Is is positive)	

2







(1) Recommended setup for high frequency: Symmetrical placement of the primary current and the return current.

CTT200ID

Isolation Specifications						
Clearance	11.5 mm					
Creepage distance	11.5 mm					
RMS voltage for AC isolation test, 50/60 Hz	z, 1 min					
Between primary and (secondary and shield)	5.7 kV					
Impulse withstand voltage (1.2/50 μs)	10.4 kV					
Continuous working voltage	Using uninsulated wire	Using insulated wire				
Non mains signals	1000 V	2000 V				
CAT II signals	600 V RMS / 600 V DC	1000 V RMS / 1000 V DC				
CAT III signals	300 V RMS / 300 V DC	1000 V RMS / 1000 V DC				
Transient voltage	Using uninsulated wire	Using insulated wire				
Non mains signals	4500 V	6000 V				
CAT II signals	6000 V	6000 V				
CAT III signals	6000 V	8000 V				

Note: Higher isolation voltages can be achieved using isolated bus bars. Contact custom systems at: customsystems@hbkworld.com.

Environmental and Safety Specifications				
Ambient operating temperature range	-40 °C to +85 °C			
Storage temperature range	-40 °C to +85 °C			
Relative humidity	20% to 80%, Non-condensing			
Maximum altitude	2000 m (6562 ft)			
Usage	Designed for indoor use			
Transient voltages	Up to overvoltage category III			
Polution Degree	2			
External devices	External devices connected to current transducers must comply with the standards IEC61010-1, IEC60950 or IEC62368-1 and be energy-limited circuitry			
Cleaning	The transducer should only be cleaned with a damp cloth. No detergent or chemicals should be used.			
Ambient Temperature	Note: When multiple primary turns are used or high primary currents are applied the temperature around the transducer will increase, please monitor to ensure that the maximum ratings are not exceeded. It is recommended to have minimum 1mm² per ampere in the primary bus-bar.			

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Harmonized Standards for CE and UKCA Compliance, According to the Following Directives (1)				
Low Voltage Directive (LVD): 2014/35/EU Electromagnetic Compatibility Directive (EMC): 2014/30/EU				
Electrical Safety				
EN 61010-1 (2017)	Safety requirements for electrical equipment for measurement, control, and laboratory use - General requirements			
EN 61010-2-030 (2017)	Particular requirements for testing and measuring circuits			
Electromagnetic Compatibi	lity			
EN 61326-1 (2013)	Electrical equipment for measurement, control and laboratory use - EMC requirements - Part 1: General requirements			
Environmental				
EN 60068-2-64:2008	Environmental testing - Part 2-64: Tests - Test Fh: Vibration, broadband random and guidance			
EN 60068-2-27:2009 Environmental testing - Part 2-27: Tests - Test Ea and guidance: Shock				

(1) La The manufacturer declares on its sole responsibility that the product is in conformity with the essential requirements of the applicable UK legislation and that the relevant conformity assessment procedures have been fulfilled.

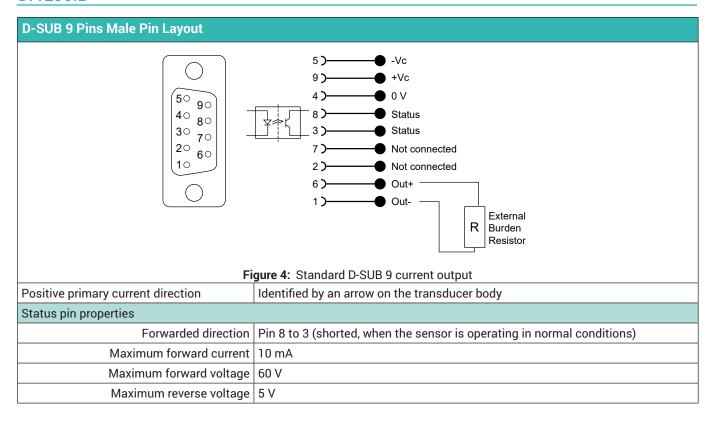
Manufacturer.

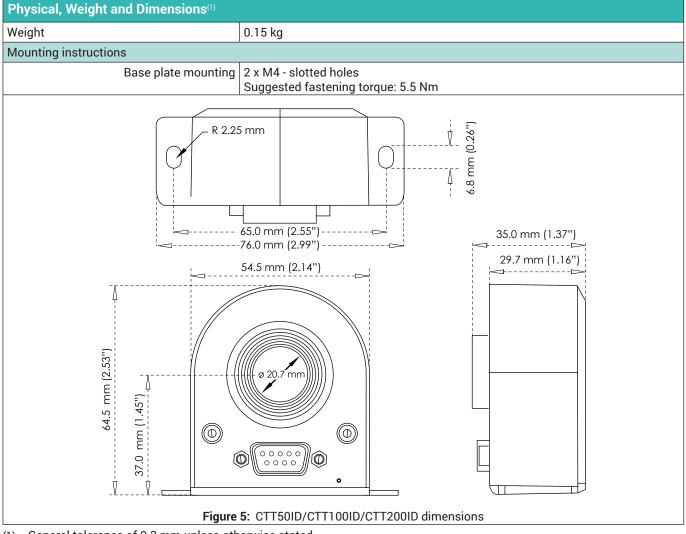
Hottinger Brüel & Kjaer GmbH

Im Tiefen See 45 64293 Darmstadt Germany Importer.

Hottinger Bruel & Kjaer UK Ltd.

Technology Centre Advanced Manufacturing Park Brunel Way Catcliffe Rotherham South Yorkshire S60 5WG United Kingdom





(1) General tolerance of 0.3 mm unless otherwise stated

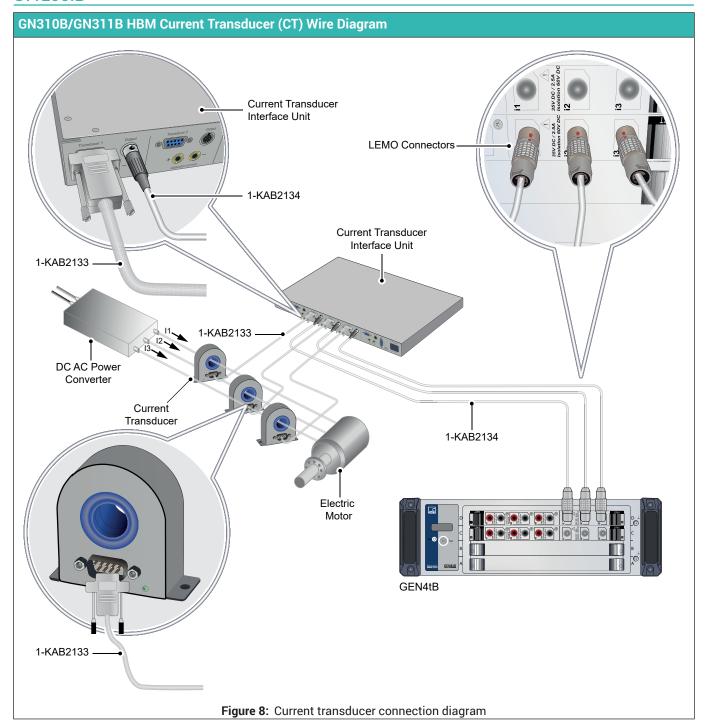
1-CTPSIU-6-1U Interface Unit for CT (Option, to be ordered separately)					
Modular 19" rack with 1 to maximum 6 channel CT support.					
- C HBM	CTPS ⁶¹ 012314551 000000000000000000000000000000000				
Fig	gure 6: Front side (left) and rear side (right)				
Maximum number of CTs	6				
Input connectors	9 pin SUBD				
Output connectors	XLR				
Signal LEDS	CT Power ON, CT Status				
Power supply	100 to 240 V AC, 47 to 63 Hz 120 - 370 V DC				
Weight	Typical 6.5 kg (14.33 lb)				
Operating temperature range	0 °C to +50 °C (32 °F to 122 °F)				
Dimensions					
Height	87.2 mm (3,43")				
Width / Width including mounting ears	442 mm (17,40") / 466 mm (18,34")				
Depth	415 mm (16,33")				
466 mm (18.3")	442 mm (17.4")				
0	CTPS@ 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0				
	Figure 7: Dimensions				

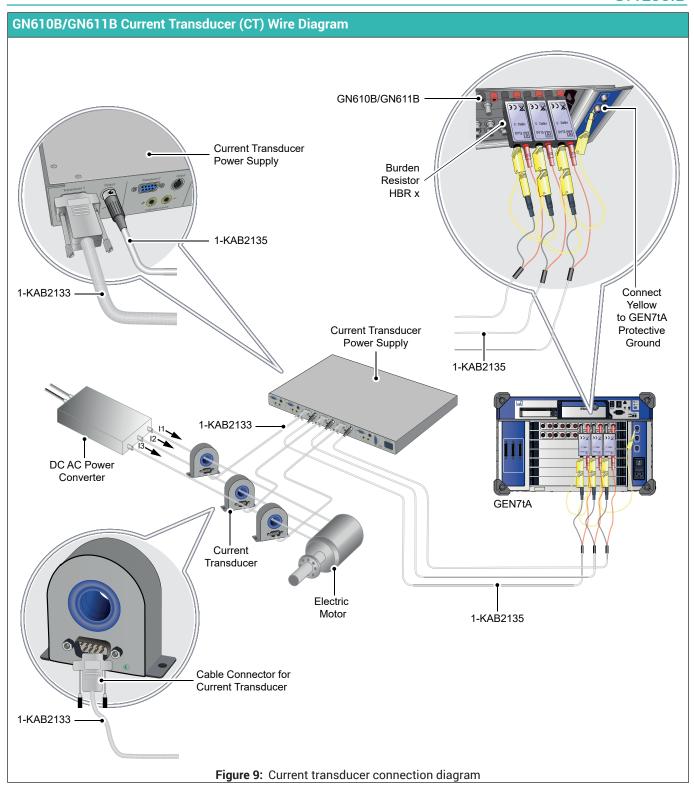
Current Transducer Family Overview					
Туре	Nominal current	Bandwidth (-3 dB)	Ratio Primary : Secundary	Aperture size	
CTT50ID	50 A RMS / 70 A DC	2000 kHz	1 : 500	20.7 mm	
CTT100ID	100 A RMS 100 A DC	2000 kHz	1:1000	20.7 mm	
CTT200ID	200 A RMS 200 A DC	2000 kHz	1:1000	20.7 mm	
CTN1000ID	1000 A RMS 1000 A DC	400 kHz	1:1500	41.2 mm	
Other values available on request ⁽¹⁾					

⁽¹⁾ Contact custom systems at: customsystems@hbkworld.com.

Request quote/information for special products for GEN series.

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Ordering Information					
Article		Description	Order No.		
200 A DC or 200 A RMS current transducer		Ultra-stable, high-precision fluxgate technology current transducer. Non-intrusive isolated DC and AC current measurement up to 200 A RMS / 200 A DC. Full aluminum body for superior EMI shielding. Extended operating temperature range. Large aperture Ø 20.7 mm for cables and bus bars. Industry standard D-Sub 9 pin connection.	1-CTT200ID		

Current Transdu	Current Transducers Interface and Cables, to be ordered separately				
Article		Description	Order No.		
CT Interface unit	COSS	Interface unit for up to six current transducers. Industry standard D-SUB 9 pin input connectors. Multi-pin XLR output connectors. Supports transducer calibration winding access through 4 mm banana plugs. Front LEDs to indicate normal operation of each transducer. 100 - 240 V AC 50/60 Hz AC input voltage. 120 - 370 V DC input voltage. 1U height 19" rack mountable.	1-CTPSIU-6-1U		
CT cables		Industry standard current transducer connection cable. Shielded, low ohmic 9 wire cable with D-SUB 9 connectors on both ends. Supports power, status, current output and calibration current input. Lengths: 2, 5, 10 and 20 meters (6, 16, 32 and 65 ft)	1-KAB2133-2 1-KAB2133-5 1-KAB2133-10 1-KAB2133-15 1-KAB2133-20		
XLR to LEMO cable for GN31XB		CT interface unit to GN31xB DAQ power card connection cable. Uses XLR and LEMO connectors for a direct current output connection to the GEN DAQ card. Length 2 m (6 ft)	1-KAB2134-2		
XLR to Banana cable for GN61XB		CT interface unit to GN61xB DAQ 1kV card connection cable. Uses XLR and banana connectors for a current output connection to the GEN DAQ card. Requires an additional burden resistor in front of the GN61xB card to convert current to voltage. Length 2 m (6 ft)	1-KAB2135-2		

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GN610B/GN611B Burden Resistors, to be ordered separately

Burden selection for GN610B/GN611B

Note: When using the CTS/CTM series together with GN610B/GN611B cards a burden resistor is required to convert the CT output current to a voltage. When selecting the burden several specifications need to be taken into account: maximum power of the burden, maximum voltage the CT can drive with constant current, the wire impedance of the cables used etc. See the CT operating manual for more details.

Model	Recommended burden	mV/A sensitivity	A/V scaling
CTT50ID	HBR 2.5 Ω	5.0	200
CTT100ID	HBR 1.0 Ω	2.0	500
CTT200ID	HBR 1.0 Ω	0.5	2000
CTN1000ID	HBR 1.0 Ω	0.6667	1500

Article		Description	Order No
HBR 0.25 Ω, 1 W precision burden resistor	MORO 20	0.25Ω 1 W, 0.02% high precision, low thermal drift burden resistor. Internally uses 4 wire connection to reduce inaccuracy caused by the currents running to the burden resistor. Using banana input connectors and banana output pins. Directly compatible with GN610B/GN611B acquisition cards.	Ordered from custom systems ⁽¹⁾
HBR 0.5 Ω, 1 W precision burden resistor	MAS MAS	$0.5~\Omega 1$ W, 0.02% high precision, low thermal drift burden resistor. Internally uses 4 wire connection to reduce inaccuracy caused by the currents running to the burden resistor. Using banana input connectors and banana output pins. Directly compatible with GN610B/GN611B acquisition cards.	Ordered from custom systems ⁽¹⁾
HBR 1 Ω, 1 W precision burden resistor	Monto	$1~\Omega, 1~W, 0.02\%$ high precision, low thermal drift burden resistor. Internally uses 4 wire connection to reduce inaccuracy caused by the currents running to the burden resistor. Using banana input connectors and banana output pins. Directly compatible with GN610B/GN611B acquisition cards.	Ordered from custom systems ⁽¹⁾
HBR 2.5 Ω, 1 W precision burden resistor	HEREZ O	$2.5\Omega,1$ W, 0.02% high precision, low thermal drift burden resistor. Internally uses 4 wire connection to reduce inaccuracy caused by the currents running to the burden resistor. Using banana input connectors and banana output pins. Directly compatible with GN610B/GN611B acquisition cards.	Ordered from custom systems ⁽¹⁾
HBR 10 Ω, 1 W precision burden resistor	MORTO NERTO	$10~\Omega, 1~W, 0.02\%$ high precision, low thermal drift burden resistor. Internally uses 4 wire connection to reduce inaccuracy caused by the currents running to the burden resistor. Using banana input connectors and banana output pins. Directly compatible with GN610B/GN611B acquisition cards.	Ordered from custom systems ⁽¹⁾

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Hottinger Brüel & Kjaer GmbH

Im Tiefen See 45 · 64293 Darmstadt · Germany Tel. +49 6151 803-0 · Fax +49 6151 803-9100 www.hbkworld.com · info@hbkworld.com